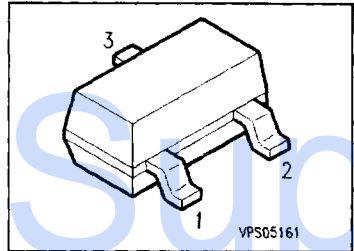


NPN Silicon AF Transistors

**BCW 60
BCX 70**

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BCW 61, BCX 71 (PNP)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BCW 60 A	AAs	Q62702-C1517	B	E	C	SOT-23
BCW 60 B	ABs	Q62702-C1497				
BCW 60 C	ACs	Q62702-C1476				
BCW 60 D	ADs	Q62702-C1477				
BCW 60 FF	AFs	Q62702-C1529				
BCW 60 FN	ANs	Q62702-C1567				
BCX 70 G	AGs	Q62702-C1539				
BCX 70 H	AHs	Q62702-C1481				
BCX 70 J	AJs	Q62702-C1552				
BCX 70 K	AKs	Q62702-C1571				

¹⁾ For detailed information see chapter Package Outlines.

Maximum Ratings

Parameter	Symbol	Values			Unit
		BCW 60	BCW 60 FF	BCX 70	
Collector-emitter voltage	V_{CE0}	32	32	45	V
Collector-base voltage	V_{CB0}	32	32	45	
Emitter-base voltage	V_{EB0}	5			
Collector current	I_C	100			mA
Peak collector current	I_{CM}	200			
Peak base current	I_{BM}	200			
Total power dissipation, $T_S = 71\text{ °C}$	P_{tot}	330			mW
Junction temperature	T_j	150			°C
Storage temperature range	T_{stg}	- 65 ... + 150			

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 310	K/W
Junction - soldering point	$R_{th JS}$	≤ 240	

¹⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit			
		min.	typ.	max.				
DC characteristics								
Collector-emitter breakdown voltage $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	32 45	— —	— —	V			
BCW 60, BCW 60 FF BCX 70								
Collector-base breakdown voltage $I_C = 10\ \mu\text{A}$	$V_{(BR)CBO}$	32 45	— —	— —				
BCW 60, BCW 60 FF BCX 70								
Emitter-base breakdown voltage $I_E = 1\ \mu\text{A}$	$V_{(BR)EBO}$	5	—	—				
Collector cutoff current $V_{CB} = 32\text{ V}$	I_{CBO}	—	—	20	nA			
BCW 60, BCW 60 FF								
$V_{CB} = 45\text{ V}$				20	nA			
BCX 70								
$V_{CB} = 32\text{ V}, T_A = 150^\circ\text{C}$		—	—	20	μA			
BCW 60, BCW 60 FF								
$V_{CB} = 45\text{ V}, T_A = 150^\circ\text{C}$		—	—	20	μA			
BCX 70								
Emitter cutoff current $V_{EB} = 4\text{ V}$	I_{EBO}	—	—	20	nA			
DC current gain ¹⁾ $I_C = 10\ \mu\text{A}, V_{CE} = 5\text{ V}$	h_{FE}				—			
BCW 60 A, BCX 70 G						20	140	—
BCW 60 B, BCX 70 H						20	200	—
BCW 60 FF, BCW 60 C, BCX 70 J						40	300	—
BCW 60 FN, BCW 60 D, BCX 70 K						100	460	—
$I_C = 2\text{ mA}, V_{CE} = 5\text{ V}$								
BCW 60 A, BCX 70 G						120	170	220
BCW 60 B, BCX 70 H						180	250	310
BCW 60 FF, BCW 60 C, BCX 70 J						250	350	460
BCW 60 FN, BCW 60 D, BCX 70 K						380	500	630
$I_C = 50\text{ mA}, V_{CE} = 1\text{ V}$								
BCW 60 A, BCX 70 G						50	—	—
BCW 60 B, BCX 70 H	70	—	—					
BCW 60 FF, BCW 60 C, BCX 70 J	90	—	—					
BCW 60 FN, BCW 60 D, BCX 70 K	100	—	—					

¹⁾ Pulse test: $t \leq 300\ \mu\text{s}, D \leq 2\%$.

Electrical Characteristics

at $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC characteristics					
Collector-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{CEsat}	–	0.12 0.20	0.25 0.55	V
Base-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$, $I_B = 1.25\text{ mA}$	V_{BEsat}	–	0.70 0.83	0.85 1.05	
Base-emitter voltage $I_C = 10\ \mu\text{A}$, $V_{CE} = 5\text{ V}$ $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$ $I_C = 50\text{ mA}$, $V_{CE} = 1\text{ V}$ ¹⁾	$V_{BE(on)}$	– 0.55	0.52 0.65 0.78	– 0.75 –	

AC characteristics

Transition frequency $I_C = 20\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 100\text{ MHz}$	f_T	–	250	–	MHz
Output capacitance $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{obo}	–	3	–	pF
Input capacitance $V_{EB} = 0.5\text{ V}$, $f = 1\text{ MHz}$	C_{ibo}	–	8	–	
Short-circuit input impedance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 60 A, BCX 70 G BCW 60 B, BCX 70 H BCW 60 FF, BCW 60 C, BCX 70 J BCW 60 FN, BCW 60 D, BCX 70 K	h_{11e}	–	2.7 3.6 4.5 7.5	– – – –	k Ω
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 60 A, BCX 70 G BCW 60 B, BCX 70 H BCW 60 FF, BCW 60 C, BCX 70 J BCW 60 FN, BCW 60 D, BCX 70 K	h_{12e}	–	1.5 2.0 2.0 3.0	– – – –	10^{-4}

¹⁾ Pulse test: $t \leq 300\ \mu\text{s}$, $D \leq 2\%$.

Electrical Characteristics

at $T_A = 25^\circ\text{C}$, unless otherwise specified.

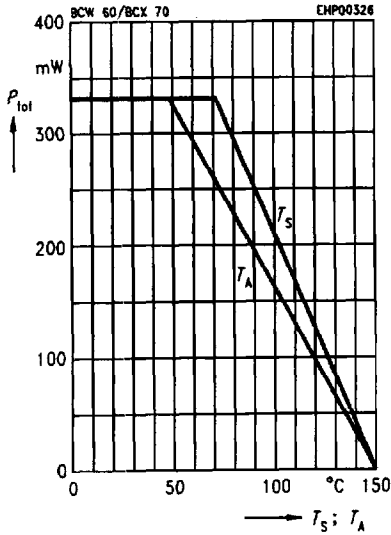
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

AC characteristics

Short-circuit forward current transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 60 A, BCX 70 G BCW 60 B, BCX 70 H BCW 60 FF, BCW 60 C, BCX 70 J BCW 60 FN, BCW 60 D, BCX 70 K	h_{21e}	—	200	—	—
		—	260	—	
		—	330	—	
		—	520	—	
Open-circuit output admittance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BCW 60 A, BCX 70 G BCW 60 B, BCX 70 H BCW 60 FF, BCW 60 C, BCX 70 J BCW 60 FN, BCW 60 D, BCX 70 K	h_{22e}	—	18	—	μS
		—	24	—	
		—	30	—	
		—	50	—	
Noise figure $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 1\text{ kHz}$, $\Delta f = 200\text{ Hz}$ BCW 60 A to BCX 70 K BCW 60 FF, BCW 60 FN	F	—	2	—	dB
		—	1	2	
Equivalent noise voltage $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BCW 60 FF, BCW 60 FN	V_n	—	—	0.135	μV

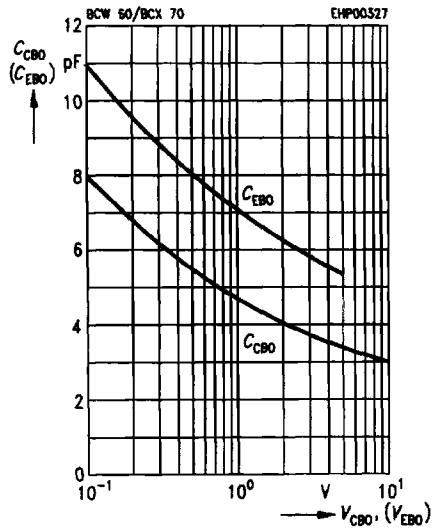
Total power dissipation $P_{tot} = f(T_A^*; T_S)$

* Package mounted on epoxy



Collector-base capacitance $C_{CBO} = f(V_{CBO})$

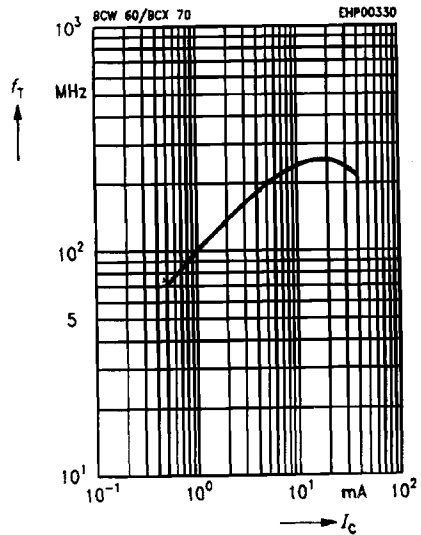
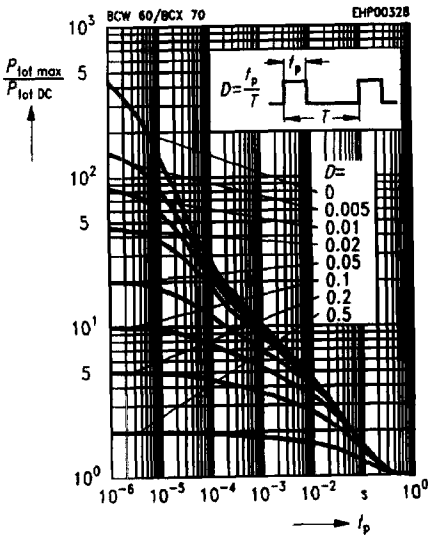
Emitter-base capacitance $C_{EBO} = f(V_{EBO})$



Permissible pulse load $P_{tot max}/P_{tot DC} = f(t_p)$

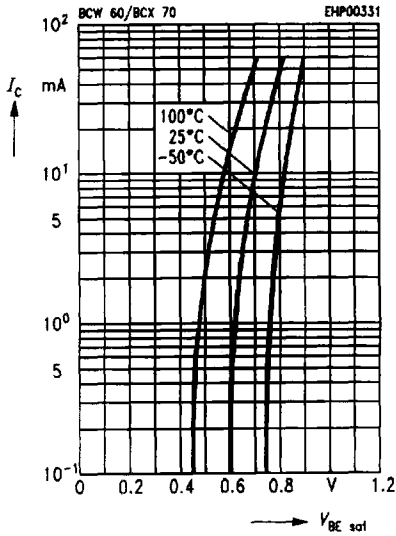
Transition frequency $f_T = f(I_C)$

$V_{CE} = 5 V$



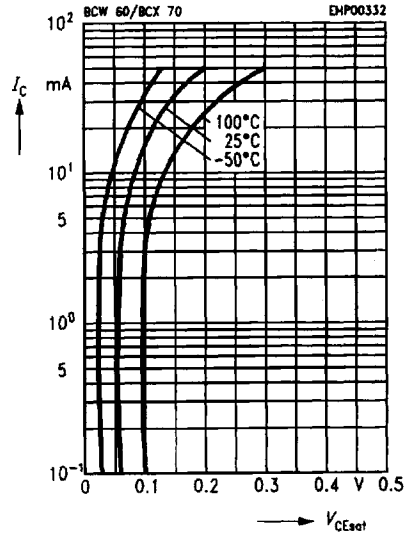
Base-emitter saturation voltage

$I_C = f(V_{BEsat})$
 $h_{FE} = 40$



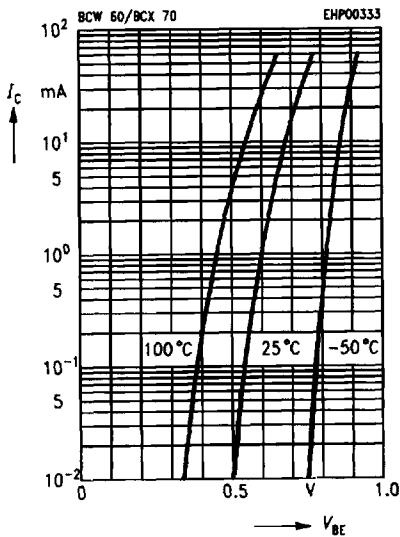
Collector-emitter saturation voltage

$I_C = f(V_{CEsat})$
 $h_{FE} = 40$



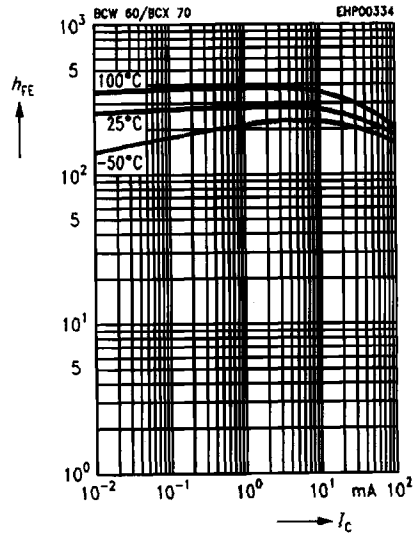
Collector current $I_C = f(V_{BE})$

$V_{CE} = 5 V$



DC current gain $h_{FE} = f(I_C)$

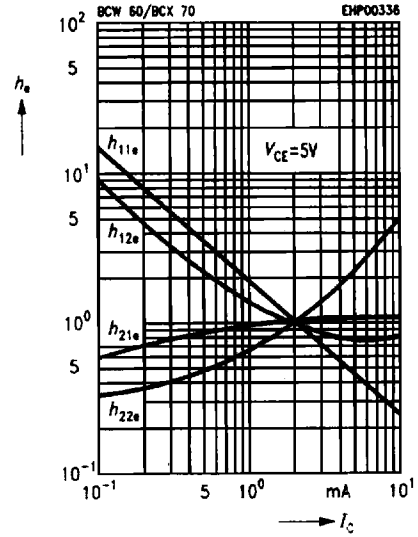
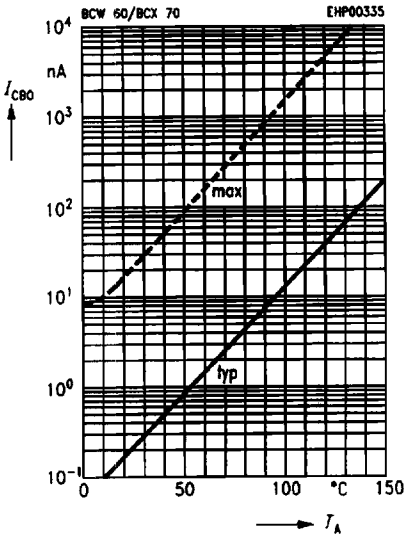
$V_{CE} = 5 V$



Collector cutoff current $I_{CBO} = f(T_A)$

h parameter $h_e = f(I_C)$

$V_{CE} = 5\text{ V}$

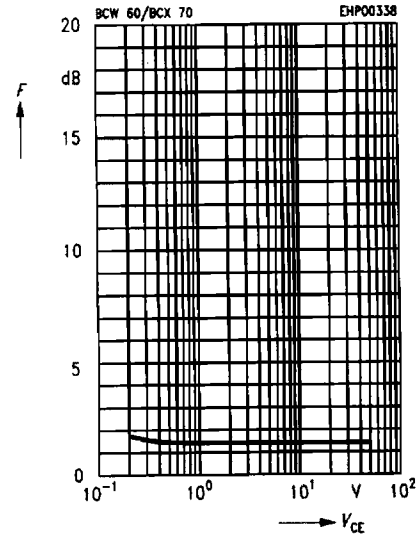
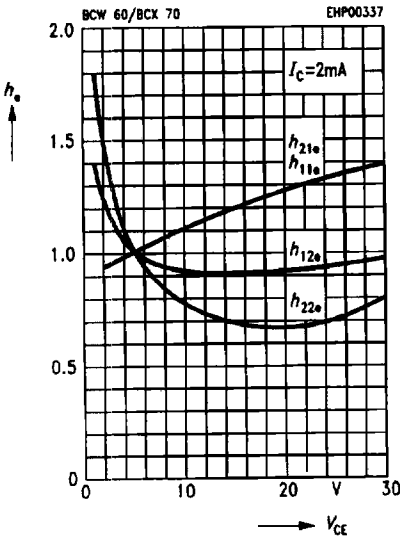


h parameter $h_e = f(V_{CE})$

$I_C = 2\text{ mA}$

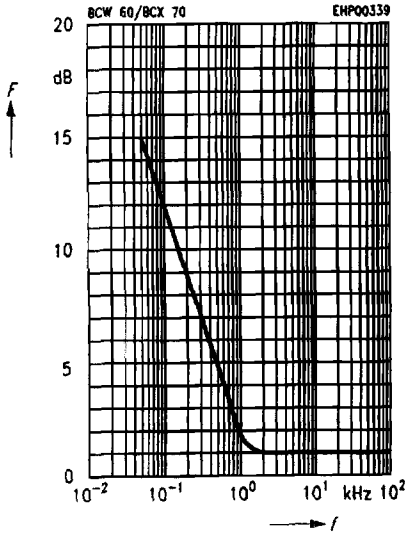
Noise figure $F = f(V_{CE})$

$I_C = 0.2\text{ mA}$, $R_S = 2\text{ k}\Omega$, $f = 1\text{ kHz}$



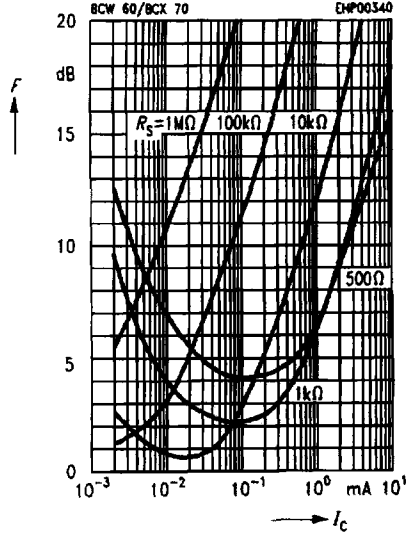
Noise figure $F = f(f)$

$I_C = 0.2 \text{ mA}$, $R_S = 2 \text{ k}\Omega$, $V_{CE} = 5 \text{ V}$



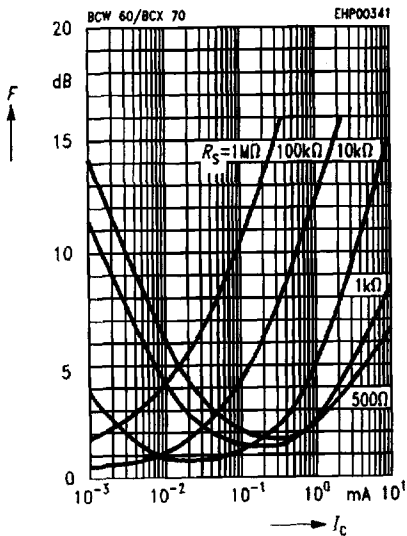
Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 120 \text{ Hz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 1 \text{ kHz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 10 \text{ kHz}$

